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xaminer nitials	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T²
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	Examiner Signature	will.	Date Considered	2/04/02
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¹ Unique citation designation number. ² Applicant is to place a check mark here if English language Translation is attached.



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